

## ESH2B-M3, ESH2C-M3, ESH2D-M3

Vishay General Semiconductor

## **Surface Mount Ultrafast Plastic Rectifier**



DO-214AA (SMB)

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2.0 A				
V <sub>RRM</sub>	100 V, 150 V, 200 V				
t <sub>rr</sub>	25 ns				
V <sub>F</sub>	0.93 V				
T <sub>J</sub> max.	175 °C				
Package	DO-214AA (SMB)				
Diode variations	Single die				

#### FEATURES

- Glass passivated pellet chip junction
- Ideal for automated placement
- Ultrafast recovery times for high efficiency
- Low forward voltage, low power loss
- High forward surge capability
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

### **TYPICAL APPLICATIONS**

For use in high frequency rectification and freewheeling application in switching mode converter and inverter for both consumer.

### **MECHANICAL DATA**

**Case:** DO-214AA (SMB) Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 2 whisker test

Polarity: Color band denotes cathode end

<b>MAXIMUM RATINGS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	SYMBOL	ESH2B	ESH2C	ESH2D	UNIT	
Device marking code		EHB	EHC	EHD		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	100	150	200	V	
Maximum RMS voltage	V <sub>RMS</sub>	70	105	140	V	
Maximum DC blocking voltage	V <sub>DC</sub>	100	150	200	V	
Maximum average forward rectified current (fig. 1)	I <sub>F(AV)</sub>	2.0			А	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	60			А	
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +175			°C	





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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT	
Maximum instantaneous forward voltage	I <sub>F</sub> = 2 A		$V_{F}$ <sup>(1)</sup>	0.93	V	
Maximum DC reverse current		T <sub>A</sub> = 25 °C	I_	2.0	μΑ	
at rated DC blocking voltage		T <sub>A</sub> = 125 °C	I <sub>R</sub>	50		
Maximum reverse recovery time	I <sub>F</sub> = 0.5 A, I <sub>R</sub> = 1 A, I <sub>rr</sub> = 0.25 A		t <sub>rr</sub>	25	ns	
Typical reverse recovery time	$I_F = 2 \text{ A}, V_R = 30 \text{ V},$ dI/dt = 50 A/µs, $I_{rr} = 10 \% I_{RM}$	T <sub>J</sub> = 25 °C	t <sub>rr</sub>	35	ns	
		$T_J = 100 \ ^\circ C$		55		
Typical stored charge	$I_F = 2 \Lambda, V_R = 30 V,$	T <sub>J</sub> = 25 °C	Q <sub>rr</sub>	20	nC	
		T <sub>J</sub> = 100 °C		35		
Typical junction capacitance	4.0 V, 1 MHz		CJ	30	pF	

#### Note

 $^{(1)}\,$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)					
PARAMETER	SYMBOL	ESH2B	ESH2C	ESH2D	UNIT
Typical thermal resistance	$R_{\theta JA}$ <sup>(1)</sup>	65			°C/W
Typical thermal resistance	$R_{\theta JL}$ <sup>(1)</sup>		C/W		

#### Note

 $^{(1)}\,$  Units mounted on PCB with 8.0 mm x 8.0 mm land areas

ORDERING INFORMATION (Example)						
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
ESH2D-M3/52T	0.096	52T	750	7" diameter plastic tape and reel		
ESH2D-M3/5BT	0.096	5BT	3200	13" diameter plastic tape and reel		

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### **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

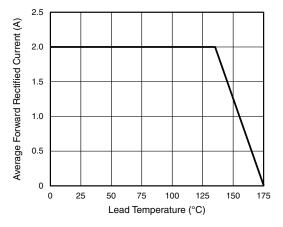


Fig. 1 - Maximum Forward Current Derating Curve

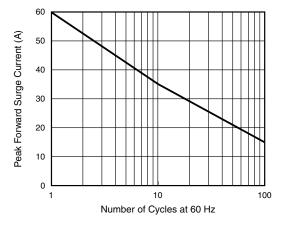


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current

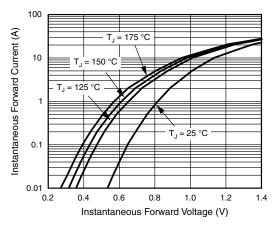


Fig. 3 - Typical Instantaneous Forward Characteristics

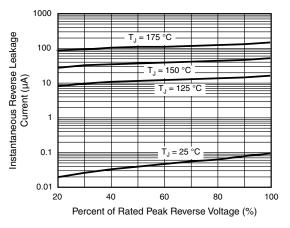


Fig. 4 - Typical Reverse Leakage Characteristics

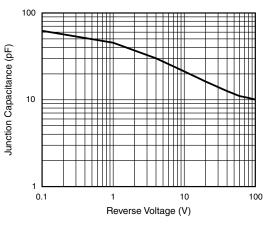


Fig. 5 - Typical Junction Capacitance

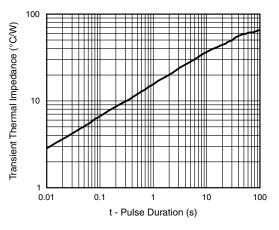


Fig. 6 - Typical Transient Thermal Impedance

Revision: 19-Feb-15

3

Document Number: 89482

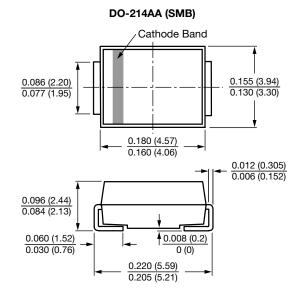
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## ESH2B-M3, ESH2C-M3, ESH2D-M3

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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

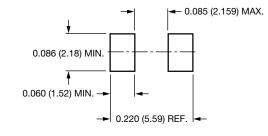


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Mounting Pad Layout





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